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"[Embedded - Microcontrollers](#)" refer to small, integrated circuits designed to perform specific tasks within larger systems. These microcontrollers are essentially compact computers on a single chip, containing a processor core, memory, and programmable input/output peripherals. They are called "embedded" because they are embedded within electronic devices to control various functions, rather than serving as standalone computers. Microcontrollers are crucial in modern electronics, providing the intelligence and control needed for a wide range of applications.

### Applications of "[Embedded - Microcontrollers](#)"

#### Details

Product Status	Obsolete
Core Processor	Coldfire V4E
Core Size	32-Bit Single-Core
Speed	200MHz
Connectivity	EBI/EMI, Ethernet, I <sup>2</sup> C, SPI, UART/USART, USB
Peripherals	DMA, PWM, WDT
Number of I/O	99
Program Memory Size	-
Program Memory Type	ROMless
EEPROM Size	-
RAM Size	32K x 8
Voltage - Supply (Vcc/Vdd)	1.43V ~ 1.58V
Data Converters	-
Oscillator Type	External
Operating Temperature	0°C ~ 70°C (TA)
Mounting Type	Surface Mount
Package / Case	388-BBGA
Supplier Device Package	388-PBGA (27x27)
Purchase URL	<a href="https://www.e-xfl.com/pro/item?MUrl=&amp;PartUrl=mcf5472zp200">https://www.e-xfl.com/pro/item?MUrl=&amp;PartUrl=mcf5472zp200</a>

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# 1 Maximum Ratings

Table 1 lists maximum and minimum ratings for supply and operating voltages and storage temperature. Operating outside of these ranges may cause erratic behavior or damage to the processor.

**Table 1. Absolute Maximum Ratings**

Rating	Symbol	Value	Units
External (I/O pads) supply voltage (3.3-V power pins)	$EV_{DD}$	-0.3 to +4.0	V
Internal logic supply voltage	$IV_{DD}$	-0.5 to +2.0	V
Memory (I/O pads) supply voltage (2.5-V power pins)	$SD V_{DD}$	-0.3 to +4.0 SDR Memory -0.3 to +2.8 DDR Memory	V
PLL supply voltage	$PLL V_{DD}$	-0.5 to +2.0	V
Internal logic supply voltage, input voltage level	$V_{in}$	-0.5 to +3.6	V
Storage temperature range	$T_{stg}$	-55 to +150	°C

## 2 Thermal Characteristics

### 2.1 Operating Temperatures

Table 2 lists junction and ambient operating temperatures.

**Table 2. Operating Temperatures**

Characteristic	Symbol	Value	Units
Maximum operating junction temperature	$T_j$	105	°C
Maximum operating ambient temperature	$T_{Amax}$	<70 <sup>1</sup>	°C
Minimum operating ambient temperature	$T_{Amin}$	-0	°C

<sup>1</sup> This published maximum operating ambient temperature should be used only as a system design guideline. All device operating parameters are guaranteed only when the junction temperature lies within the specified range.

### 2.2 Thermal Resistance

Table 3 lists thermal resistance values.

**Table 3. Thermal Resistance**

Characteristic		Symbol	Value	Unit
324 pin TEPBGA — Junction to ambient, natural convection	Four layer board (2s2p)	$\theta_{JMA}$	20–22 <sup>1,2</sup>	°CW
388 pin TEPBGA — Junction to ambient, natural convection	Four layer board (2s2p)	$\theta_{JMA}$	19 <sup>1,2</sup>	°CW

**Table 3. Thermal Resistance (continued)**

Characteristic		Symbol	Value	Unit
Junction to ambient (@200 ft/min)	Four layer board (2s2p)	$\theta_{JMA}$	16 <sup>1,2</sup>	°CW
Junction to board	—	$\theta_{JB}$	11 <sup>3</sup>	°CW
Junction to case	—	$\theta_{JC}$	7 <sup>4</sup>	°CW
Junction to top of package	Natural convection	$\Psi_{jt}$	2 <sup>1,5</sup>	°CW

<sup>1</sup>  $\theta_{JA}$  and  $\Psi_{jt}$  parameters are simulated in accordance with EIA/JESD Standard 51-2 for natural convection. Freescale recommends the use of  $\theta_{JA}$  and power dissipation specifications in the system design to prevent device junction temperatures from exceeding the rated specification. System designers should be aware that device junction temperatures can be significantly influenced by board layout and surrounding devices. Conformance to the device junction temperature specification can be verified by physical measurement in the customer's system using the  $\Psi_{jt}$  parameter, the device power dissipation, and the method described in EIA/JESD Standard 51-2.

<sup>2</sup> Per JEDEC JESD51-6 with the board horizontal.

<sup>3</sup> Thermal resistance between the die and the printed circuit board per JEDEC JESD51-8. Board temperature is measured on the top surface of the board near the package.

<sup>4</sup> Thermal resistance between the die and the case top surface as measured by the cold plate method (MIL SPEC-883 Method 1012.1).

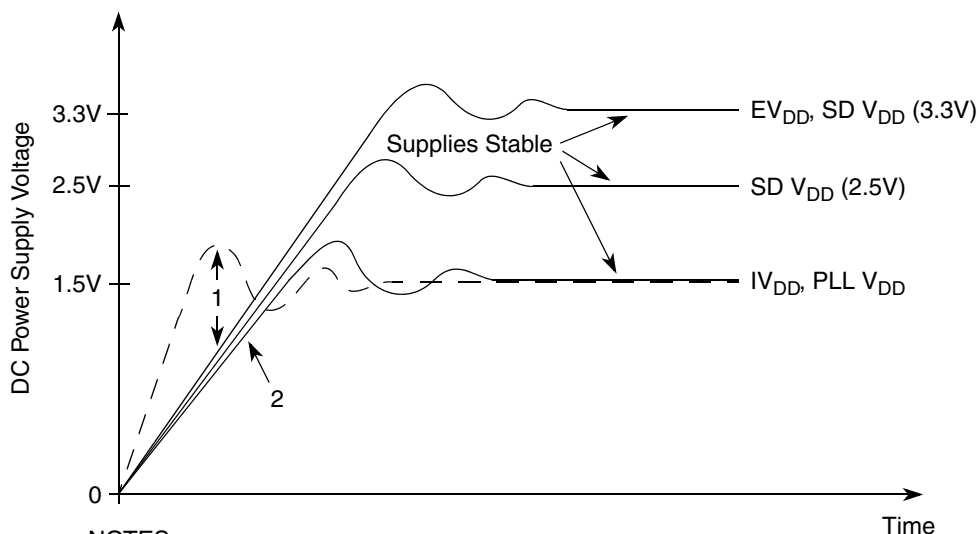
<sup>5</sup> Thermal characterization parameter indicating the temperature difference between package top and the junction temperature per JEDEC JESD51-2. When Greek letters are not available, the thermal characterization parameter is written as Psi-JT.

### 3 DC Electrical Specifications

Table 4 lists DC electrical operating temperatures. This table is based on an operating voltage of  $EV_{DD} = 3.3 V_{DC} \pm 0.3 V_{DC}$  and  $IV_{DD}$  of  $1.5 \pm 0.07 V_{DC}$ .

**Table 4. DC Electrical Specifications**

Characteristic	Symbol	Min	Max	Units
External (I/O pads) operation voltage range	$EV_{DD}$	3.0	3.6	V
Memory (I/O pads) operation voltage range (DDR Memory)	$SD V_{DD}$	2.30	2.70	V
Internal logic operation voltage range <sup>1</sup>	$IV_{DD}$	1.43	1.58	V
PLL Analog operation voltage range <sup>1</sup>	$PLL V_{DD}$	1.43	1.58	V
USB oscillator operation voltage range	$USB\_OSV_{DD}$	3.0	3.6	V
USB digital logic operation voltage range	$USBV_{DD}$	3.0	3.6	V
USB PHY operation voltage range	$USB\_PHYV_{DD}$	3.0	3.6	V
USB oscillator analog operation voltage range	$USB\_OSCAV_{DD}$	1.43	1.58	V
USB PLL operation voltage range	$USB\_PLLV_{DD}$	1.43	1.58	V
Input high voltage SSTL 3.3V/2.5V <sup>2</sup>	$V_{IH}$	$V_{REF} + 0.3$	$SD V_{DD} + 0.3$	V
Input low voltage SSTL 3.3V/2.5V <sup>2</sup>	$V_{IL}$	$V_{SS} - 0.3$	$V_{REF} - 0.3$	V
Input high voltage 3.3V I/O pins	$V_{IH}$	$0.7 \times EV_{DD}$	$EV_{DD} + 0.3$	V
Input low voltage 3.3V I/O pins	$V_{IL}$	$V_{SS} - 0.3$	$0.35 \times EV_{DD}$	V


**NOTES:**

1.  $IV_{DD}$  should not exceed  $EV_{DD}$  or  $SD V_{DD}$  by more than 0.4V at any time, including power-up.
2. Recommended that  $IV_{DD}/PLL V_{DD}$  should track  $EV_{DD}/SD V_{DD}$  up to 0.9V, then separate for completion of ramps.
3. Input voltage must not be greater than the supply voltage ( $EV_{DD}$ ,  $SD V_{DD}$ ,  $IV_{DD}$ , or  $PLL V_{DD}$ ) by more than 0.5V at any time, including during power-up.
4. Use 1 microsecond or slower rise time for all supplies.

**Figure 3. Supply Voltage Sequencing and Separation Cautions**

The relationship between  $SD V_{DD}$  and  $EV_{DD}$  is non-critical during power-up and power-down sequences.  $SD V_{DD}$  (2.5V or 3.3V) and  $EV_{DD}$  are specified relative to  $IV_{DD}$ .

## 4.2.1 Power Up Sequence

If  $EV_{DD}/SD V_{DD}$  are powered up with the  $IV_{DD}$  at 0V, the sense circuits in the I/O pads cause all pad output drivers connected to the  $EV_{DD}/SD V_{DD}$  to be in a high impedance state. There is no limit to how long after  $EV_{DD}/SD V_{DD}$  powers up before  $IV_{DD}$  must power up.  $IV_{DD}$  should not lead the  $EV_{DD}$ ,  $SD V_{DD}$ , or  $PLL V_{DD}$  by more than 0.4V during power ramp up or there is high current in the internal ESD protection diodes. The rise times on the power supplies should be slower than 1 microsecond to avoid turning on the internal ESD protection clamp diodes.

The recommended power up sequence is as follows:

1. Use 1 microsecond or slower rise time for all supplies.
2.  $IV_{DD}/PLL V_{DD}$  and  $EV_{DD}/SD V_{DD}$  should track up to 0.9V, then separate for the completion of ramps with  $EV_{DD}/SD V_{DD}$  going to the higher external voltages. One way to accomplish this is to use a low drop-out voltage regulator.

## 4.2.2 Power Down Sequence

If  $IV_{DD}/PLL V_{DD}$  are powered down first, sense circuits in the I/O pads cause all output drivers to be in a high impedance state. There is no limit on how long after  $IV_{DD}$  and  $PLL V_{DD}$  power down before  $EV_{DD}$  or  $SD V_{DD}$  must power down.  $IV_{DD}$  should not lag  $EV_{DD}$ ,  $SD V_{DD}$ , or  $PLL V_{DD}$  going low by more than 0.4V during power down or there is undesired high current in the ESD protection diodes. There are no requirements for the fall times of the power supplies.

The recommended power down sequence is as follows:

1. Drop  $IV_{DD}/PLL V_{DD}$  to 0V
2. Drop  $EV_{DD}/SD V_{DD}$  supplies

## 4.3 General USB Layout Guidelines

### 4.3.1 USB D+ and D- High-Speed Traces

1. High speed clock and the USB D+ and USB D- differential pair should be routed first.
2. Route USB D+ and USB D- signals on the top layer of the board.
3. The trace width and spacing of the USB D+ and USB D- signals should be such that the differential impedance is 90Ω.
4. Route traces over continuous planes (power and ground)—they should not pass over any power/ground plane slots or anti-etch. When placing connectors, make sure the ground plane clear-outs around each pin have ground continuity between all pins.
5. Maintain the parallelism (skew matched) between USB D+ and USB D-. These traces should be the same overall length.
6. Do not route USB D+ and USB D- traces under oscillators or parallel to clock traces and/or data buses. Minimize the lengths of high speed signals that run parallel to the USB D+ and USB D- pair. Maintain a minimum 50mil spacing to clock signals.
7. Keep USB D+ and USB D- traces as short as possible.
8. Route USB D+, USB D-, and USB VBUS signals with a minimum amount of vias and corners. Use 45° turns.
9. Stubs should be avoided as much as possible. If they cannot be avoided, stubs should be no greater than 200mils.

### 4.3.2 USB VBUS Traces

Connecting the USB VBUS pin directly to the 5V VBUS signal from the USB connector can cause long-term reliability problems in the ESD network of the processor. Therefore, use of an external voltage divider for VBUS is recommended. [Figure 4](#) and [Figure 5](#) depict possible connections for VBUS. Point A, marked in each figure, is where a 5V version of VBUS should connect. Point B, marked in each figure, is where a 3.3V version of VBUS should connect to the USB VBUS pin on the device.

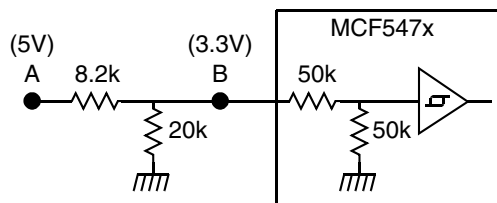


Figure 4. Preferred VBUS Connections

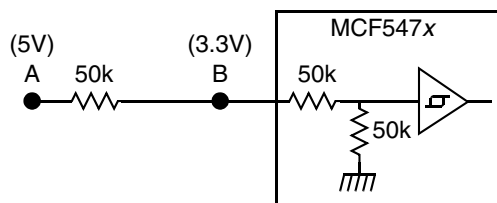


Figure 5. Alternate VBUS Connections

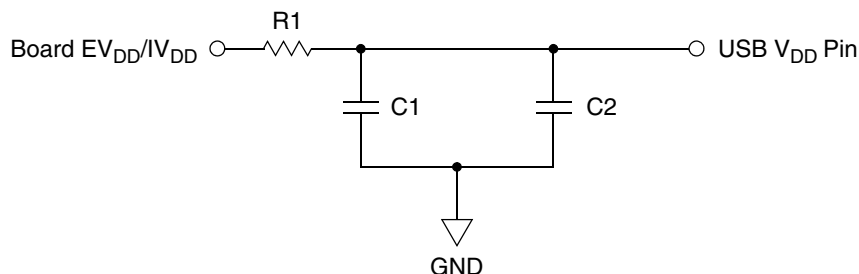
### 4.3.3 USB Receptacle Connections

It is recommended to connect the shield and the ground pin of the B USB receptacle for upstream ports to the board ground plane. The ground pin of the A USB receptacles for downstream ports should also be connected to the board ground plane, but industry practice varies widely on the connection of the shield of the A USB receptacles to other system grounds. Take precautions for control of ground loops between hosts and self-powered USB devices through the cable shield.

## 4.4 USB Power Filtering

To minimize noise, an external filter is required for each of the USB power pins. The filter shown in [Figure 6](#) should be connected between the board  $EV_{DD}$  or  $IV_{DD}$  and each of the USB  $V_{DD}$  pins.

- The resistor and capacitors should be placed as close to the dedicated USB  $V_{DD}$  pin as possible.
- A separate filter circuit should be included for each USB  $V_{DD}$  pin, a total of five circuits.
- All traces should be as low impedance as possible, especially ground pins to the ground plane.
- The filter for USB\_PHYVDD to VSS should be connected to the power and ground planes, respectively, not fingers of the planes.
- In addition to keeping the filter components for the USB\_PLLVDD as close as practical to the body of the processor as previously mentioned, special care should be taken to avoid coupling switching power supply noise or digital switching noise onto the portion of that supply between the filter and the processor.
- The capacitors for C2 in the table below should be rated X5R or better due to temperature performance.



**Figure 6. USB  $V_{DD}$  Power Filter**

### NOTE

In addition to the above filter circuitry, a 0.01 F capacitor is also recommended in parallel with those shown.

[Table 5](#) lists the resistor values and supply voltages to be used in the circuit for each of the USB  $V_{DD}$  pins.

**Table 5. USB Filter Circuit Values**

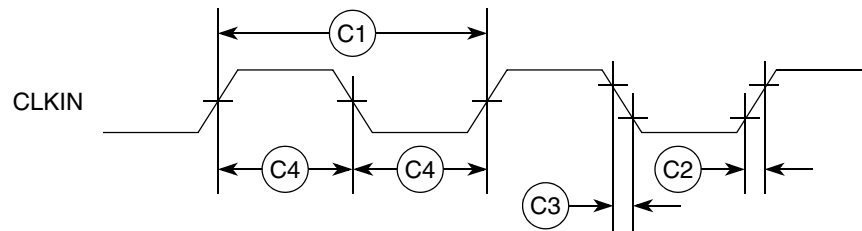
USB $V_{DD}$ Pin	Nominal Voltage	R1 ( $\Omega$ )	C1 ( $\mu$ F)	C2 ( $\mu$ F)
USBVDD (Bias generator supply)	3.3V	10	10	0.1
USB_PHYVDD (Main transceiver supply)	3.3V	0	10	0.1
USB_PLLVDD (PLL supply)	1.5V	10	1	0.1
USB_OSCVDD (Oscillator supply)	3.3V	0	10	0.1
USB_OSCAVDD (Oscillator analog supply)	1.5V	0	10	0.1

## 6 PLL Timing Specifications

The specifications in [Table 7](#) are for the CLKIN pin.

**Table 7. Clock Timing Specifications**

Num	Characteristic	Min	Max	Units
C1	Cycle time	15.0	40	ns
C2	Rise time (20% of V <sub>dd</sub> to 80% of v <sub>dd</sub> )	—	2	ns
C3	Fall time (80% of V <sub>dd</sub> to 20% of V <sub>dd</sub> )	—	2	ns
C4	Duty cycle (at 50% of V <sub>dd</sub> )	40	60	%



**Figure 8. Input Clock Timing Diagram**

[Table 8](#) shows the supported PLL encodings.

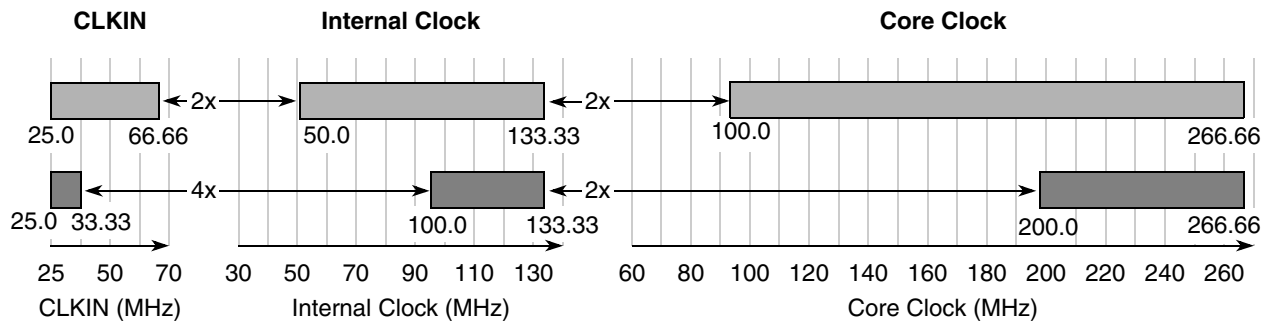
**Table 8. MCF547x Divide Ratio Encodings**

AD[12:8] <sup>1</sup>	Clock Ratio	CLKIN—PCI and FlexBus Frequency Range (MHz)	Internal XLB, SDRAM Bus, and PSTCLK Frequency Range (MHz)	Core Frequency Range (MHz)
00011	1:2	41.67–66.66	83.33–133.33	166.66–266.66
00101	1:2	25.0–44.42	50.0–88.83 <sup>2</sup>	100.0–177.66
01111	1:4	25.0–33.3	100–133.33	200–266.66

<sup>1</sup> All other values of AD[12:8] are reserved.

<sup>2</sup> DDR memories typically have a minimum speed of 83 MHz. Some vendors specify down to 75 MHz. Check with the memory component specifications to verify.

[Figure 9](#) correlates CLKIN, internal bus, and core clock frequencies for the 1x–4x multipliers.



**Figure 9. CLKIN, Internal Bus, and Core Clock Ratios**



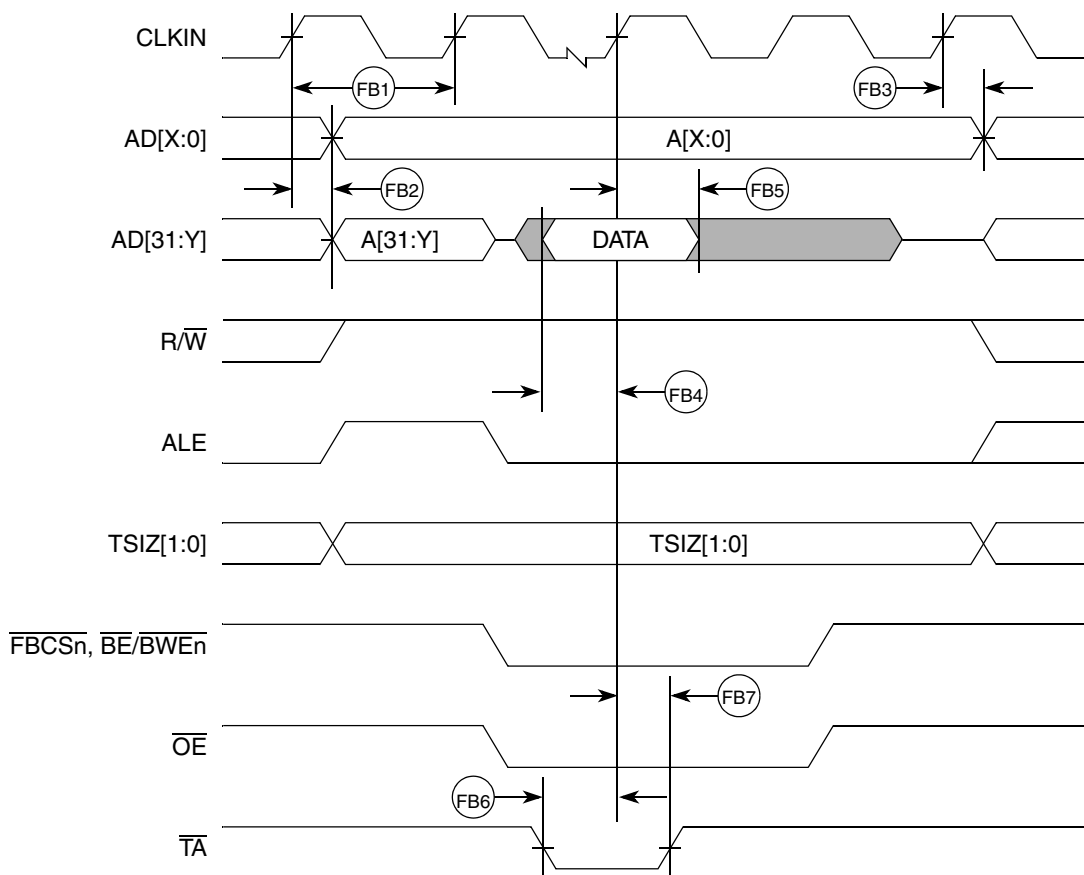


Figure 11. FlexBus Read Timing

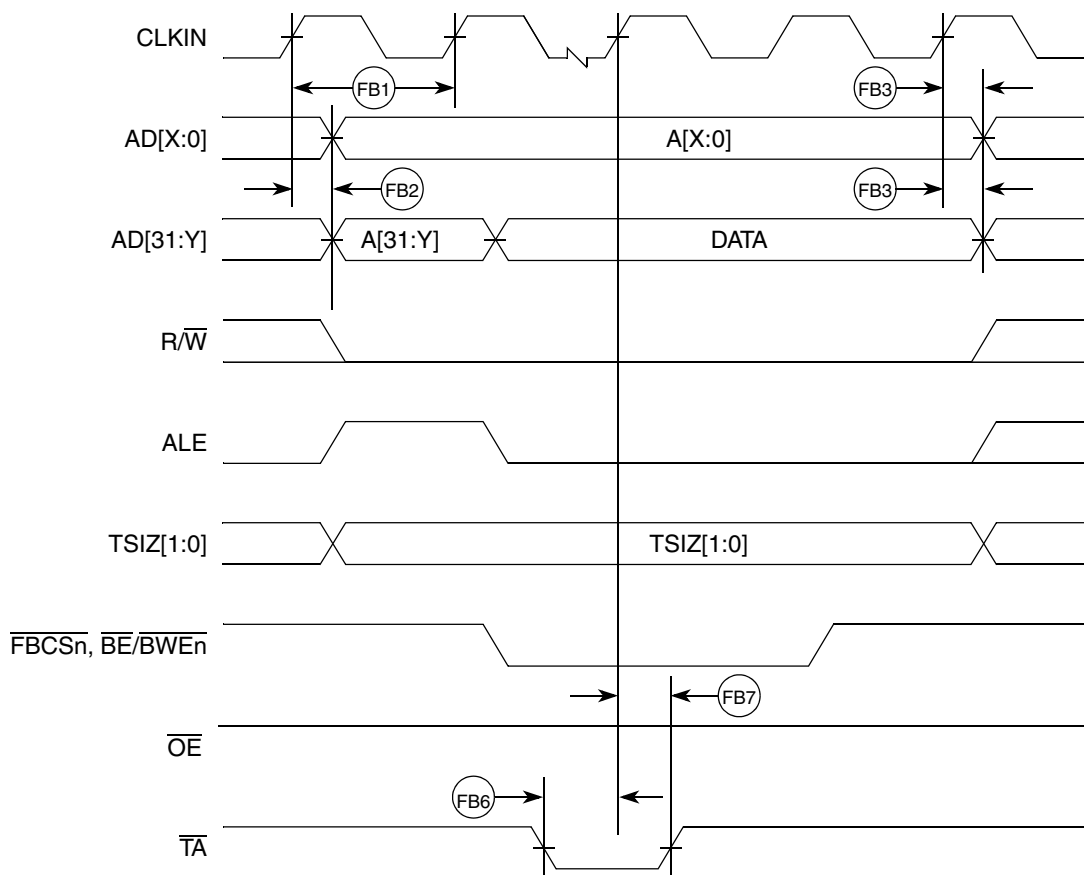


Figure 12. FlexBus Write Timing

## 9 SDRAM Bus

The SDRAM controller supports accesses to main SDRAM memory from any internal master. It supports standard SDRAM or double data rate (DDR) SDRAM, but it does not support both at the same time. The SDRAM controller uses SSTL2 and SSTL3 I/O drivers. Both SSTL drive modes are programmable for Class I or Class II drive strength.

### 9.1 SDR SDRAM AC Timing Characteristics

The following timing numbers indicate when data is latched or driven onto the external bus, relative to the memory bus clock, when operating in SDR mode on write cycles and relative to SDR\_DQS on read cycles. The MCF547x SDRAM controller is a DDR controller that has an SDR mode. Because it is designed to support DDR, a DQS pulse must be supplied to the MCF547x for each data beat of an SDR read. The MCF547x accomplishes this by asserting a signal called SDR\_DQS during read cycles. Care must be taken during board design to adhere to the following guidelines and specs with regard to the SDR\_DQS signal and its usage.

**Table 11. SDR Timing Specifications**

Symbol	Characteristic	Min	Max	Unit	Notes
	Frequency of Operation	0	133	Mhz	1
SD1	Clock Period ( $t_{CK}$ )	7.52	12	ns	2
SD2	Clock Skew ( $t_{SK}$ )		TBD		
SD3	Pulse Width High ( $t_{CKH}$ )	0.45	0.55	SDCLK	3
SD4	Pulse Width Low ( $t_{CKL}$ )	0.45	0.55	SDCLK	4
SD5	Address, CKE, CAS, RAS, WE, BA, CS - Output Valid ( $t_{CMV}$ )		$0.5 \times \text{SDCLK} + 1.0\text{ns}$	ns	
SD6	Address, CKE, CAS, RAS, WE, BA, CS - Output Hold ( $t_{CMH}$ )	2.0		ns	
SD7	SDRDQS Output Valid ( $t_{DQSOV}$ )		Self timed	ns	5
SD8	SDDQS[3:0] input setup relative to SDCLK ( $t_{DQSiS}$ )	$0.25 \times \text{SDCLK}$	$0.40 \times \text{SDCLK}$	ns	6
SD9	SDDQS[3:0] input hold relative to SDCLK ( $t_{DQSiH}$ )	Does not apply. 0.5 SDCLK fixed width.			7
SD10	Data Input Setup relative to SDCLK (reference only) ( $t_{DiS}$ )	$0.25 \times \text{SDCLK}$		ns	8
SD11	Data Input Hold relative to SDCLK (reference only) ( $t_{DiH}$ )	1.0		ns	
SD12	Data and Data Mask Output Valid ( $t_{DV}$ )		$0.75 \times \text{SDCLK} + 0.500\text{ns}$	ns	
SD13	Data and Data Mask Output Hold ( $t_{DH}$ )	1.5		ns	

<sup>1</sup> The frequency of operation is 2x or 4x the CLKIN frequency of operation. The MCF547X supports a single external reference clock (CLKIN). This signal defines the frequency of operation for FlexBus and PCI, but SDRAM clock operates at the same frequency as the internal bus clock. Please see the PLL chapter of the *MCF547X Reference Manual* for more information on setting the SDRAM clock rate.

<sup>2</sup> SDCLK is one SDRAM clock in (ns).

<sup>3</sup> Pulse width high plus pulse width low cannot exceed min and max clock period.

<sup>4</sup> Pulse width high plus pulse width low cannot exceed min and max clock period.

<sup>5</sup> SDR\_DQS is designed to pulse 0.25 clock before the rising edge of the memory clock. This is a guideline only. Subtle variation from this guideline is expected. SDR\_DQS only pulses during a read cycle and one pulse occurs for each data beat.

<sup>6</sup> SDR\_DQS is designed to pulse 0.25 clock before the rising edge of the memory clock. This spec is a guideline only. Subtle variation from this guideline is expected. SDR\_DQS only pulses during a read cycle and one pulse occurs for each data beat.

<sup>7</sup> The SDR\_DQS pulse is designed to be 0.5 clock in width. The timing of the rising edge is most important. The falling edge does not affect the memory controller.

<sup>8</sup> Because a read cycle in SDR mode uses the DQS circuit within the MCF547X, it is most critical that the data valid window be centered 1/4 clk after the rising edge of DQS. Ensuring that this happens results in successful SDR reads. The input setup spec is provided as guidance.

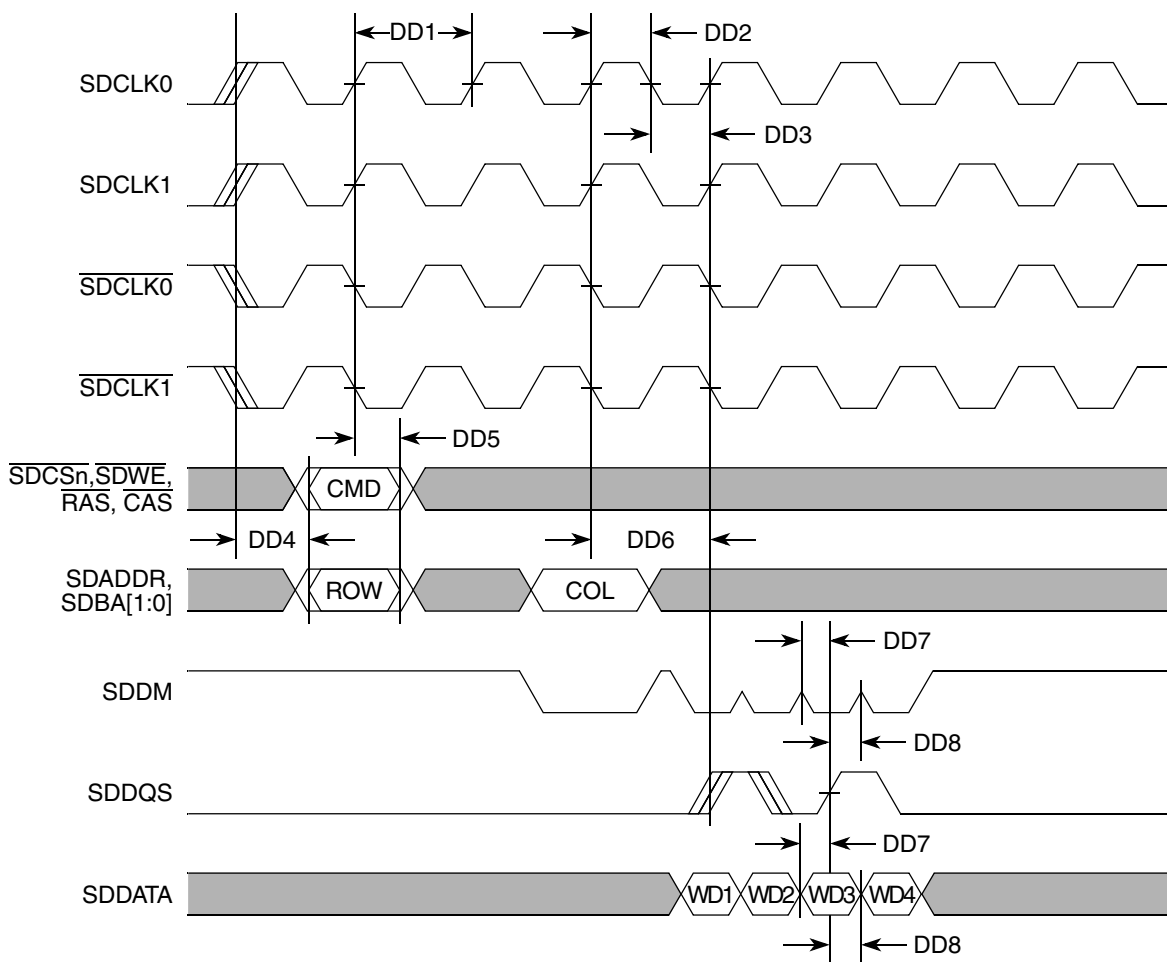
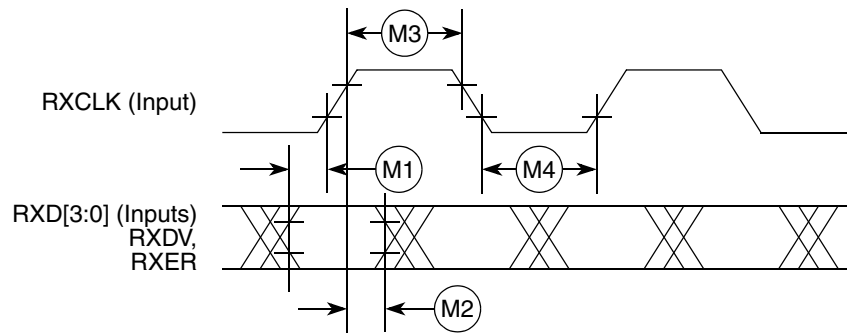


Figure 16. DDR Write Timing

**Table 15. MII Receive Signal Timing**

Num	Characteristic	Min	Max	Unit
M1	RXD[3:0], RXDV, RXER to RXCLK setup	5	—	ns
M2	RXCLK to RXD[3:0], RXDV, RXER hold	5	—	ns
M3	RXCLK pulse width high	35%	65%	RXCLK period
M4	RXCLK pulse width low	35%	65%	RXCLK period

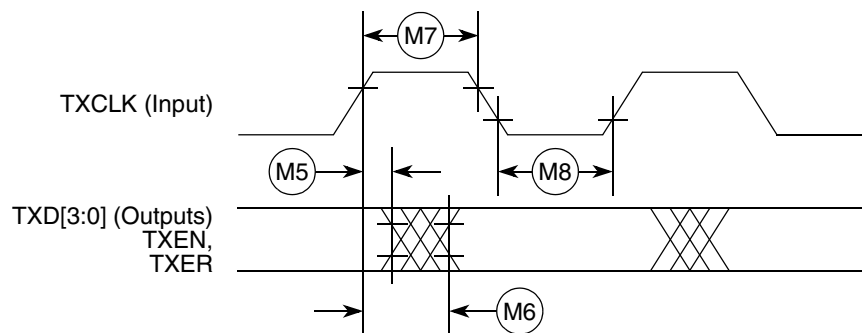


**Figure 19. MII Receive Signal Timing Diagram**

## 11.2 MII Transmit Signal Timing

**Table 16. MII Transmit Signal Timing**

Num	Characteristic	Min	Max	Unit
M5	TXCLK to TXD[3:0], TXEN, TXER invalid	0	—	ns
M6	TXCLK to TXD[3:0], TXEN, TXER valid	—	25	ns
M7	TXCLK pulse width high	35%	65%	TXCLK period
M8	TXCLK pulse width low	35%	65%	TXCLK period



**Figure 20. MII Transmit Signal Timing Diagram**

### 11.3 MII Async Inputs Signal Timing (CRS, COL)

Table 17. MII Transmit Signal Timing

Num	Characteristic	Min	Max	Unit
M9	CRS, COL minimum pulse width	1.5	—	TX_CLK period

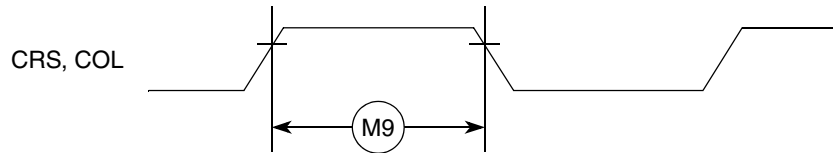


Figure 21. MII Async Inputs Timing Diagram

### 11.4 MII Serial Management Channel Timing (MDIO, MDC)

Table 18. MII Serial Management Channel Signal Timing

Num	Characteristic	Min	Max	Unit
M10	MDC falling edge to MDIO output invalid (min prop delay)	0	—	ns
M11	MDC falling edge to MDIO output valid (max prop delay)	—	25	ns
M12	MDIO (input) to MDC rising edge setup	10	—	ns
M13	MDIO (input) to MDC rising edge hold	0	—	ns
M14	MDC pulse width high	40%	60%	MDC period
M15	MDC pulse width low	40%	60%	MDC period

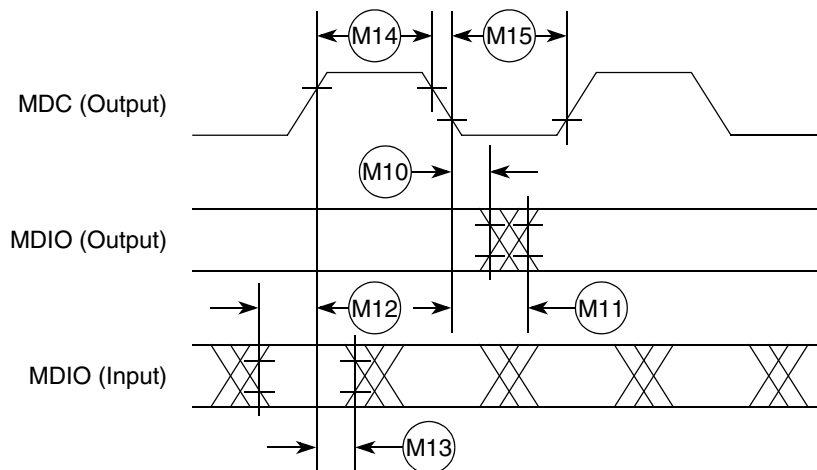


Figure 22. MII Serial Management Channel Timing Diagram

## 12 General Timing Specifications

Table 19 lists timing specifications for the GPIO, PSC,  $\overline{\text{DREQ}}$ ,  $\overline{\text{DACK}}$ , and external interrupts.

**Table 19. General AC Timing Specifications**

Name	Characteristic	Min	Max	Unit
G1	CLKIN high to signal output valid	—	2	PSTCLK
G2	CLKIN high to signal invalid (output hold)	0	—	ns
G3	Signal input pulse width	2	—	PSTCLK

## 13 I<sup>2</sup>C Input/Output Timing Specifications

Table 20 lists specifications for the I<sup>2</sup>C input timing parameters shown in Figure 23.

**Table 20. I<sup>2</sup>C Input Timing Specifications between SCL and SDA**

Num	Characteristic	Min	Max	Units
I1	Start condition hold time	2	—	Bus clocks
I2	Clock low period	8	—	Bus clocks
I3	SCL/SDA rise time ( $V_{IL} = 0.5 \text{ V}$ to $V_{IH} = 2.4 \text{ V}$ )	—	1	mS
I4	Data hold time	0	—	ns
I5	SCL/SDA fall time ( $V_{IH} = 2.4 \text{ V}$ to $V_{IL} = 0.5 \text{ V}$ )	—	1	mS
I6	Clock high time	4	—	Bus clocks
I7	Data setup time	0	—	ns
I8	Start condition setup time (for repeated start condition only)	2	—	Bus clocks
I9	Stop condition setup time	2	—	Bus clocks

Table 21 lists specifications for the I<sup>2</sup>C output timing parameters shown in Figure 23.

**Table 21. I<sup>2</sup>C Output Timing Specifications between SCL and SDA**

Num	Characteristic	Min	Max	Units
I1 <sup>1</sup>	Start condition hold time	6	—	Bus clocks
I2 <sup>1</sup>	Clock low period	10	—	Bus clocks
I3 <sup>2</sup>	SCL/SDA rise time ( $V_{IL} = 0.5 \text{ V}$ to $V_{IH} = 2.4 \text{ V}$ )	—	—	$\mu\text{S}$
I4 <sup>1</sup>	Data hold time	7	—	Bus clocks
I5 <sup>3</sup>	SCL/SDA fall time ( $V_{IH} = 2.4 \text{ V}$ to $V_{IL} = 0.5 \text{ V}$ )	—	3	ns
I6 <sup>1</sup>	Clock high time	10	—	Bus clocks
I7 <sup>1</sup>	Data setup time	2	—	Bus clocks
I8 <sup>1</sup>	Start condition setup time (for repeated start condition only)	20	—	Bus clocks
I9 <sup>1</sup>	Stop condition setup time	10	—	Bus clocks

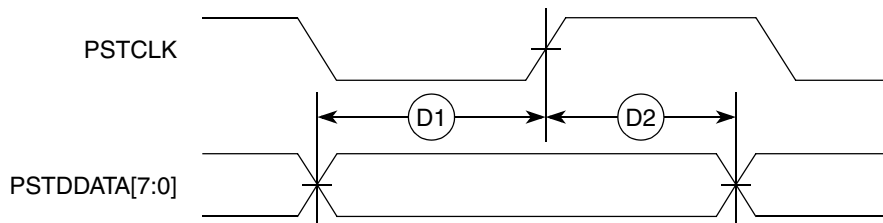
Table 23 lists specifications for the debug AC timing parameters shown in Figure 29.

**Table 23. Debug AC Timing Specifications**

Num	Characteristic	66 MHz		Units
		Min	Max	
D1	PSTDDATA to PSTCLK setup	4.5	—	ns
D2	PSTCLK to PSTDDATA hold	4.5	—	ns
D3	DSI-to-DSCLK setup	1	—	PSTCLKs
D4 <sup>1</sup>	DSCLK-to-DSO hold	4	—	PSTCLKs
D5	DSCLK cycle time	5	—	PSTCLKs

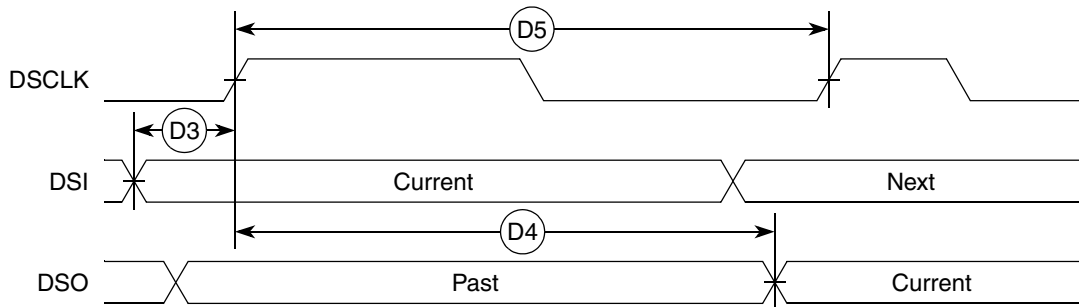
<sup>1</sup> DSCLK and DSI are synchronized internally. D4 is measured from the synchronized DSCLK input relative to the rising edge of CLKOUT.

Figure 28 shows real-time trace timing for the values in Table 23.



**Figure 28. Real-Time Trace AC Timing**

Figure 29 shows BDM serial port AC timing for the values in Table 23.



**Figure 29. BDM Serial Port AC Timing**



## 15 DSPI Electrical Specifications

Table 24 lists DSPI timings.

Table 24. DSPI Modules AC Timing Specifications

Name	Characteristic	Min	Max	Unit
DS1	DSPI_CS[3:0] to DSPI_CLK	$1 \times t_{ck}$	$510 \times t_{ck}$	ns
DS2	DSPI_CLK high to DSPI_DOUT valid.	—	12	ns
DS3	DSPI_CLK high to DSPI_DOUT invalid. (Output hold)	2	—	ns
DS4	DSPI_DIN to DSPI_CLK (Input setup)	10	—	ns
DS5	DSPI_DIN to DSPI_CLK (Input hold)	10	—	ns

The values in Table 24 correspond to Figure 30.

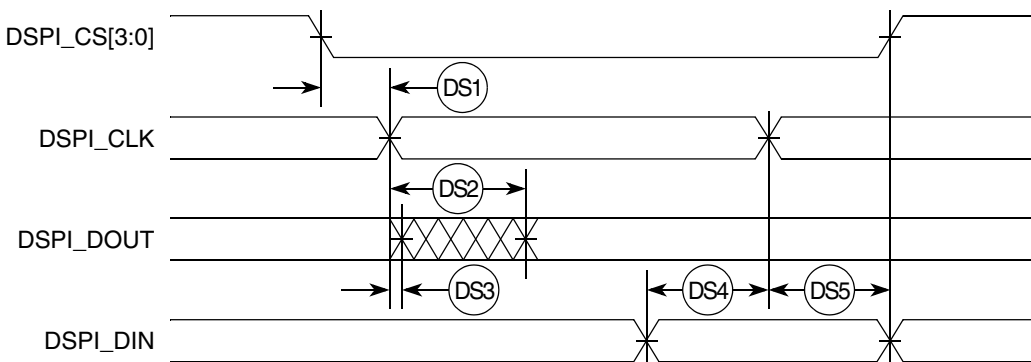


Figure 30. DSPI Timing


## 16 Timer Module AC Timing Specifications

Table 25 lists timer module AC timings.

Table 25. Timer Module AC Timing Specifications

Name	Characteristic	0–66 MHz		Unit
		Min	Max	
T1	TIN0 / TIN1 / TIN2 / TIN3 cycle time	3	—	PSTCLK
T2	TIN0 / TIN1 / TIN2 / TIN3 pulse width	1	—	PSTCLK

NOTES:

1. ALL DIMENSIONS IN MILLIMETERS.
2. DIMENSIONING AND TOLERANCING PER ASME Y14.5M-1994.
3. MAXIMUM SOLDER BALL DIAMETER MEASURED PARALLEL TO DATUM A.
4.  DATUM A, THE SEATING PLANE, IS DETERMINED BY THE SPHERICAL CROWNS OF THE SOLDER BALLS.
5. PACKAGE CODES:  
     5254 - 2 LAYER SUBSTRATE PACKAGE  
     5367 - 4 LAYER SUBSTRATE PACKAGE

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	CASE NUMBER: 1164-02	25 JAN 2007	
	STANDARD: JEDEC MS-034 AAL-1		

**Figure 31. 388-pin BGA Case Outline**

# 18 Revision History

Revision Number	Date	Substantive Changes
2.2	August 29, 2005	<a href="#">Table 7</a> : Changed C1 maximum spec from 33.3 ns to 40 ns.
2.3	August 30, 2005	<a href="#">Table 22</a> : Changed J11 maximum from 15 ns to 20 ns.
2.4	December 14, 2005	<a href="#">Table 10</a> : Changed FB1 maximum from 33.33 ns to 40 ns. <a href="#">Table 14</a> : Changed FB1 maximum from 33.33 ns to 40 ns.
3	February 20, 2007	<a href="#">Table 4</a> : Updated DC electrical specifications, $V_{IL}$ and $V_{IH}$ . <a href="#">Table 6</a> : Changed FlexBus output load from 20pF to 30pF. Added <a href="#">Section 4.3</a> , "General USB Layout Guidelines."
4	December 4, 2007	<a href="#">Figure 2</a> : Changed resistor value from 10W to 10 $\Omega$ <a href="#">Figure 3</a> : Changed note 1 in from "IVDD should not exceed EVDD, SD VDD or PLL VDD by more than 0.4V..." to "IVDD should not exceed EVDD or SD VDD by more than 0.4V..." <a href="#">Table 3</a> : Updated thermal information for $\theta_{JMA}$ , $\theta_{JB}$ , and $\theta_{JC}$ <a href="#">Table 4</a> : Added input leakage current spec. <a href="#">Table 6</a> : Added footnote regarding pads having balanced source & sink current. <a href="#">Table 9</a> : Added $\overline{RSTI}$ pulse duration spec. Added features list, pinout drawing, block diagram, and case outline.

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